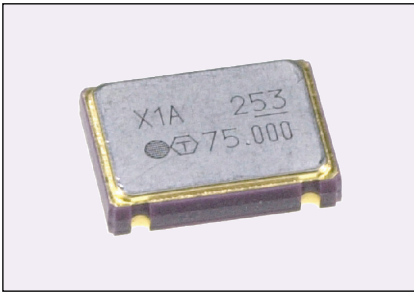


Crystal Clock Oscillator



TCO-7086X1A

SMO-N-K CMOS

Features

- CMOS logic output
- Ceramic package
- Space savings
- Enable / Disable feature

Specifications

Absolute Maximum Ratings

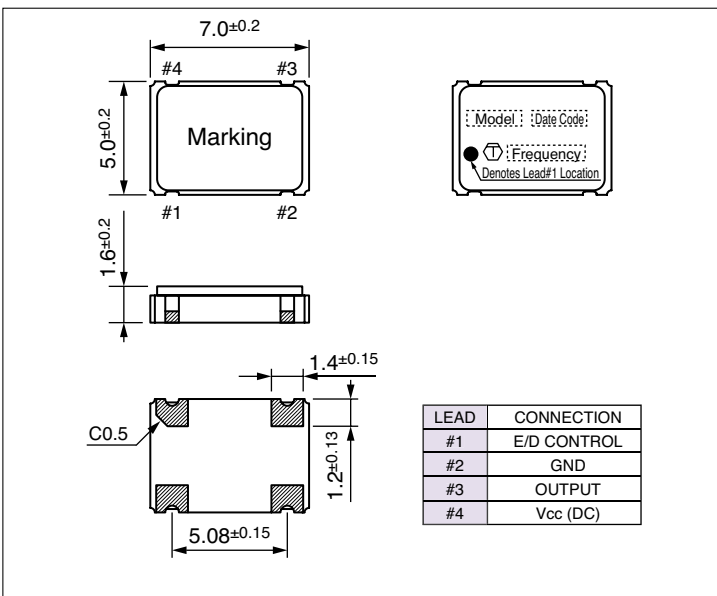
Parameter	Symbol	Rating
Supply voltage	V _{CC}	-0.5 to +7.0 V
Input voltage	V _{IN}	-0.5 to V _{CC} +0.5 V
Output voltage	V _O	-0.5 to V _{CC} +0.5 V
Input current	I _{IN}	±10 mA
Output current	I _O	±25 mA
Storage temperature	T _{stg}	-55 to +125 °C
Soldering condition	T _{sol} T	+260°C / 20sec or +230°C / 180sec

Parameter		TCO-7086X1A	Conditions
Frequency	f _o	1.5 to 75 MHz	—
Frequency Stability	Δf/f _o	±50 ppm max.	(*1)
Operating Temperature	T _{opr}	0 °C to +70 °C	—
Supply Voltage	V _{CC}	+3.3 V ±10 %	DC
Supply Current	I _{CC}	20mA max.	V _{CC} = +3.63V
Input Voltage	V _{IH} V _{IL}	V _{IH} =70 % V _{CC} min. / V _{IL} =30 % V _{CC} max.	#1:V _{IH} or OPEN ... Enable #1:V _{IL} or GND ... Disable
Output Voltage	V _{OH} V _{OL}	V _{OH} =90 % V _{CC} min. / V _{OL} =10 % V _{CC} max.	I _{OH} =-5mA, I _{OL} =+5mA at V _{CC} =+2.97V
Symmetry	SYM	40 to 60 %	at 50% V _{CC}
Rise/Fall time	tr/tf	6 ns max.	at 10% to 90% V _{CC}
Load Capacitance	CL	15 pF max.	—
Start-up time	t _{st}	10 ms max.	(*2)

*1 Inclusive of calibration tolerance at +25°C, operating temperature, operating voltage range.

*2 Rise time (0 to +2.97V) of V_{CC} > 150μs

Package Outlines [Dimensions in mm]



Test Circuit

See Test Circuit page TEST-4

Footprint [Dimensions in mm]

